

### FCP20N60\_F080 Information

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For Reference Only

Part Number FCP20N60\_F080

ManufacturerFairchild/ON SemiconductorCategoryDiscrete Semiconductor ProductsTransistors - FETs, MOSFETs - Single

**Description** MOSFET N-CH 600V 20A TO-220

Package TO-220-3

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



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## **Certified Quality**

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









# FCP20N60\_F080 Specifications

Manufacturer Part NumberFCP20N60_F080ManufacturerFairchild/ON SemiconductorCategoryDiscrete Semiconductor ProductsTransistors - FETs, MOSFETs - SinglePackageTO-220-3SeriesSuperFET?FET TypeN-ChannelTechnologyMOSFET (Metal Oxide)Drain to Source Voltage (Vdss)600VCurrent - Continuous Drain (Id) @ 25°C20A (Tc)Drive Voltage (Max Rds On, Min Rds On)10VVgs(th) (Max) @ Id5V @ 250μA	
Category  Discrete Semiconductor Products  Transistors - FETs, MOSFETs - Single  Package  TO-220-3  Series  SuperFET?  FET Type  N-Channel  Technology  MOSFET (Metal Oxide)  Drain to Source Voltage (Vdss)  Current - Continuous Drain (Id) @ 25°C  Drive Voltage (Max Rds On, Min Rds On)  Discrete Semiconductor Products  Transistors - FETs, MOSFETs - Single  TO-220-3  SuperFET?  N-Channel  204  105  107  108  108  109  109	
Transistors - FETs, MOSFETs - Single  Package TO-220-3 Series SuperFET? FET Type N-Channel Technology MOSFET (Metal Oxide) Drain to Source Voltage (Vdss) Current - Continuous Drain (Id) @ 25°C Drive Voltage (Max Rds On, Min Rds On)  Transistors - FETs, MOSFETs - Single TO-220-3 SuperFET? N-Channel N-Channel N-Channel 10V	
Package TO-220-3 Series SuperFET?  FET Type N-Channel Technology MOSFET (Metal Oxide) Drain to Source Voltage (Vdss) 600V Current - Continuous Drain (Id) @ 25°C 20A (Tc) Drive Voltage (Max Rds On, Min Rds On) 10V	
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Drive Voltage (Max Rds On, Min Rds On) 10V	
Vgs(th) (Max) @ Id 5V @ 250uA	
1 8 20 m	
Gate Charge (Qg) (Max) @ Vgs 98nC @ 10V	
Input Capacitance (Ciss) (Max) @ Vds 3080pF @ 25V	
Vgs (Max) ±30V	
FET Feature -	
Power Dissipation (Max) 208W (Tc)	
Rds On (Max) @ Id, Vgs 190 mOhm @ 10A, 10V	
Operating Temperature $-55^{\circ}\text{C} \sim 150^{\circ}\text{C} \text{ (TJ)}$	
Mounting Type Through Hole	
Supplier Device Package TO-220-3	
Package / Case TO-220-3	
Repo	

### FCP20N60\_F080 Guarantees



#### **Quality Guarantees**

We provide 90 days warranty. \*

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



#### **Service Guarantees**

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

### FCP20N60\_F080 Payment Methods



















# FCP20N60\_F080 Shipping Methods













If you have any question about FCP20N60\_F080, please do not hesitate to contact us!

Website: https://www.heisener.com E-mail: salesdept@heisener.com